Quad SPST CMOS Analog Switch with Latches

FEATURES

- Accepts 150-ns Write Pulse Width
- 5-V On-Chip Regulator
- Latches Are Transparent with $\overline{WR}$ Low
- Low On-Resistance: 60 Ω

BENEFITS

- Compatible with Most μP Buses
- Allows Wide Power Supply Tolerance Without Affecting TTL Compatibility
- Reduced Power Consumption
- Allows Flexibility of Design

APPLICATIONS

- μP Based Systems
- Automatic Test Equipment
- Communication Systems
- Data Acquisition Systems
- Medical Instrumentation
- Factory Automation

DESCRIPTION

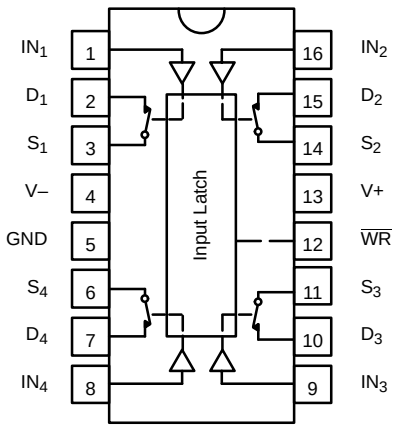
The DG221B is a monolithic quad single-pole, single-throw analog switch designed for precision switching applications in communication, instrumentation and process control systems. Featuring independent onboard latches and a common $\overline{WR}$ pin, each DG221B can be memory mapped, and addressed as a single data byte for simultaneous switching.

The DG221B combines low power and low on-resistance (60 Ω typical) while handling continuous currents up to 20 mA. An epitaxial layer prevents latchup.

The device features true bidirectional performance in the on condition.

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

Dual-In-Line and SOIC



Top View

Four Latchable SPST Switches per Package

TRUTH TABLE

IN_X	$\overline{WR}$	Switch
0	0	ON
1	0	OFF
X	↓	Control data latched-in, switches on or off as selected by last IN_X
X	1	Maintains previous state

Logic “0” ≤ 0.8 V
Logic “1” ≥ 2.4 V

ORDERING INFORMATION

Temp Range	Package	Part Number
–40°C to 85°C	16-Pin Plastic DIP	DG221BDJ
	16-Pin Narrow SOIC	DG221BDY

ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to V–
V+ . . . . . 34 V
GND . . . . . 25 V
Digital Inputs[a], V_S, V_D . . . . . (V–) –2 V to (V+) +2 V
or 20 mA, whichever occurs first
Continuous Current (Any Terminal) . . . . . 30 mA
Continuous Current, S or D . . . . . 20 mA
Peak Current, S or D (Pulsed 1 ms, 10% duty cycle) . . . . . 70 mA

Storage Temperature: (DJ and DY Suffix) . . . . . –65 to 125°C
Power Dissipation (Package)[b]
16-Pin Plastic DIP[c] . . . . . 470 mW
16-Pin SOIC[d] . . . . . 600 mW

Notes:
a. Signals on S_X, D_X, or IN_X exceeding V+ or V– will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC Board.
c. Derate 6.5 mW/°C above 25°C
d. Derate 7.7 mW/°C above 75°C

SCHEMATIC DIAGRAM (TYPICAL CHANNEL)

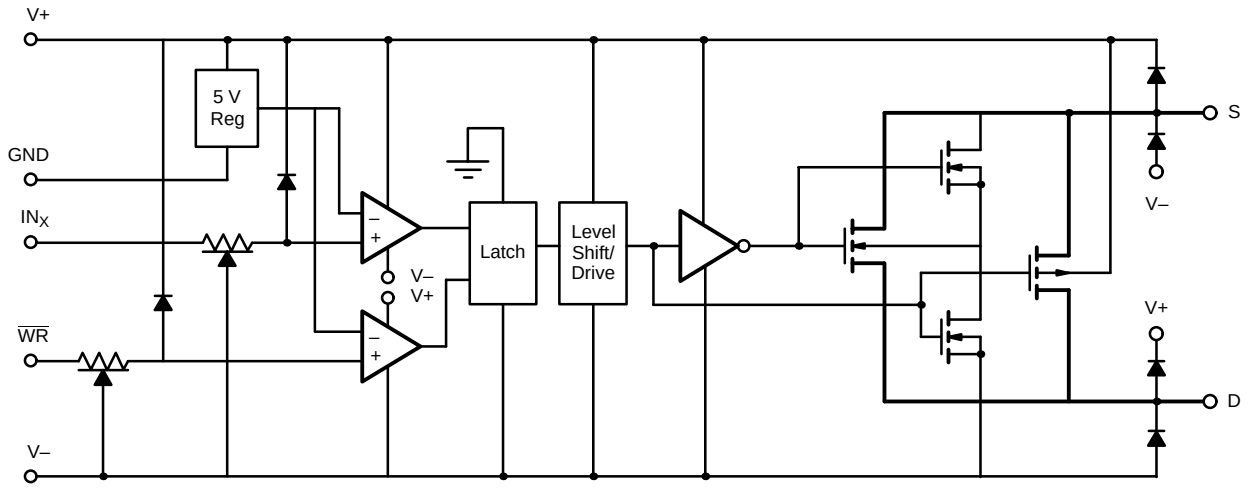


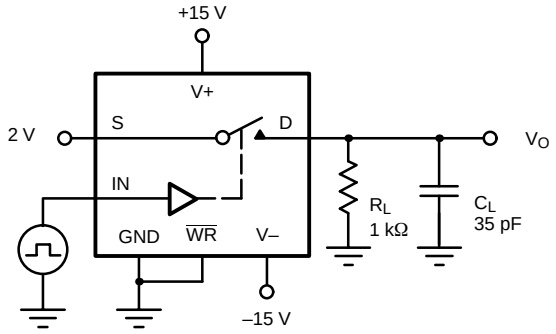
FIGURE 1.

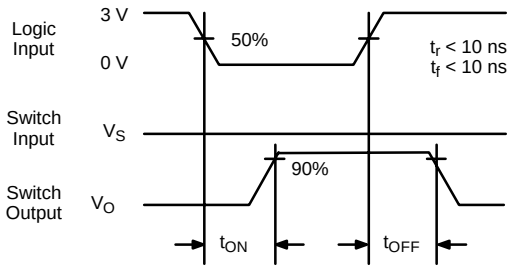
SPECIFICATIONS[a]

Parameter	Symbol	Test Conditions Unless Otherwise Specified V+ = 15 V, V– = –15 V V_{IN} = 2.4 V, 0.8[f] V, $\overline{WR}$ = 0	Temp[b]	Limits –40 to 85°C Min[d]	Typ[c]	Max[d]	Unit
Analog Switch							
Analog Signal Range[e]	V_{ANALOG}		Full	–15		15	V
Drain-Source On-Resistance	$r_{DS(on)}$	I_S = –10 mA, V_D = ±10 V	Room Full		60	90 135	Ω
Source Off Leakage Current	$I_{S(off)}$	V_S = ±14 V, V_D = ∓14 V	Room Full	–5 –100	±0.01	5 100	nA
Drain Off Leakage Current	$I_{D(off)}$		Room Full	–5 –100	±0.02	5 100	
Drain On Leakage Current	$I_{D(on)}$	V_S = V_D = ±14 V	Room Full	–5 –200	±0.01	5 200	
Digital Control							
Input Current	I_{INL}, I_{INH}	V_{IN} = 0 V or = 2.4 V	Room Full	–1 –10	–0.0004	1 10	µA
Dynamic Characteristics							
Turn-On Time	t_{ON}	See Figure 2	Room			550	ns
Turn-Off Time	t_{OFF}		Room			340	
Turn-On Time Write	t_{ON}, $\overline{WR}$	See Figure 3	Room			550	
Turn-Off Time Write	t_{OFF}, $\overline{WR}$		Room			340	
Write Pulse Width	t_W	See Figure 4	Room	150	120		
Input Setup Time	t_S		Room	180	130		
Input Hold Time	t_H		Room	20	18		
Charge Injection	Q	C_L = 1000 pF V_{GEN} = 0 V, R_{GEN} = 0 Ω	Room		20		pC
Source-Off Capacitance	$C_{S(off)}$	f = 1 MHz, V_S, V_D = 0 V	Room		8		pF
Drain-Off Capacitance	$C_{D(off)}$		Room		9		
Channel-On Capacitance	$C_{D(on)}$		Room		29		
Off Isolation	OIRR	V_S = 1 V_{p-p}, f = 100 kHz C_L = 15 pF, R_L = 1 kΩ	Room		70		dB
Interchannel Crosstalk	X_{TALK}		Room		90		
Power Supplies							
Positive Supply Current	I+	All Channels On or Off V_{IN} = 0 V or 2.4 V	Full		0.8	1.5	mA
Negative Supply Current	I–		Room	–1	–0.4		

Notes:
a. Refer to PROCESS OPTION FLOWCHART.
b. Room = 25°C, Full = as determined by the operating temperature suffix.
c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
e. Guaranteed by design, not subject to production test.
f. V_{IN} = input voltage to perform proper function.

TEST CIRCUITS

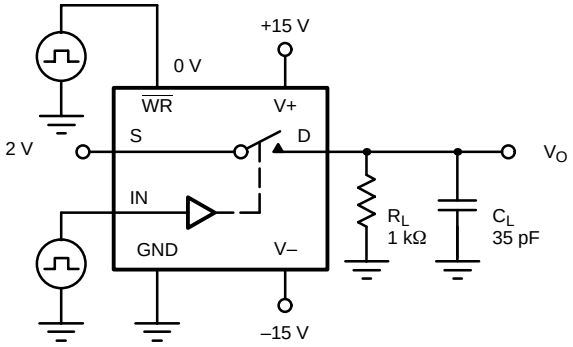


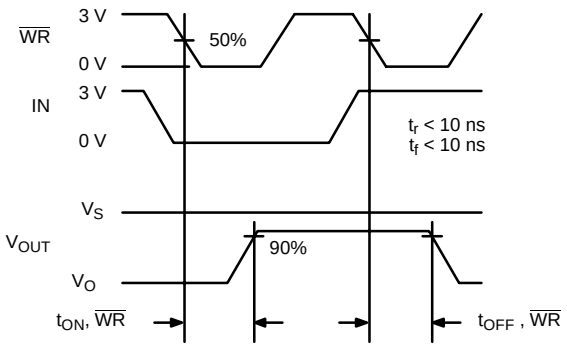


C_L (includes fixture and stray capacitance)

$$V_O = V_S \frac{R_L}{R_L + r_{DS(on)}}$$

FIGURE 2. Switching Time

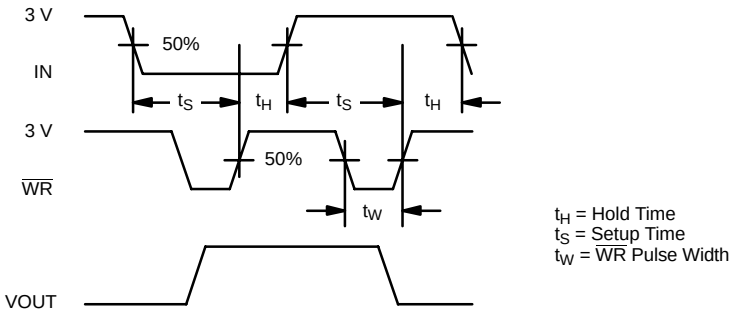




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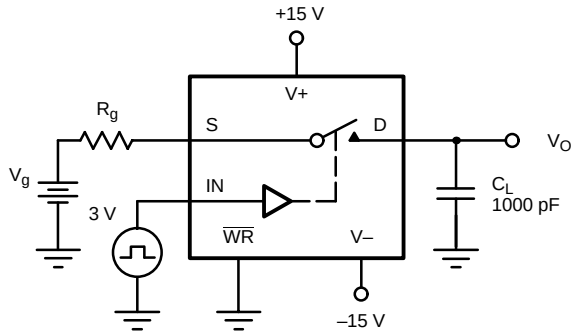
FIGURE 3. $\overline{WR}$ Switching Time

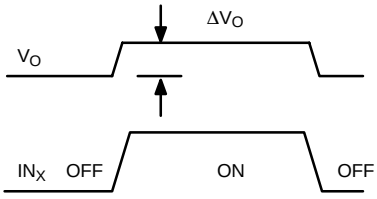


The latches are level sensitive. When $\overline{WR}$ is held low the latches are transparent and the switches respond to the digital inputs. The digital inputs are latched on the rising edge of $\overline{WR}$.

FIGURE 4. $\overline{WR}$ Setup Conditions

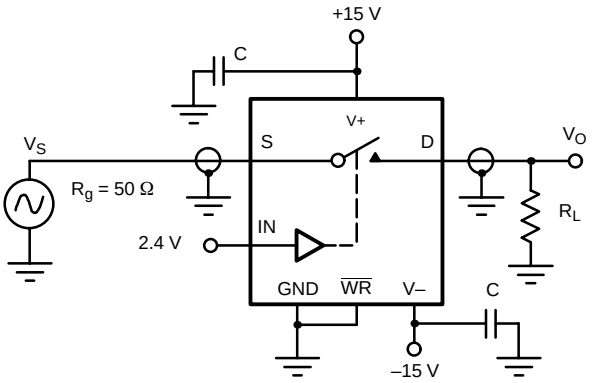
TEST CIRCUITS





ΔV_O = measured voltage error due to charge injection
The charge injection in coulombs is $Q = C_L \times \Delta V_O$

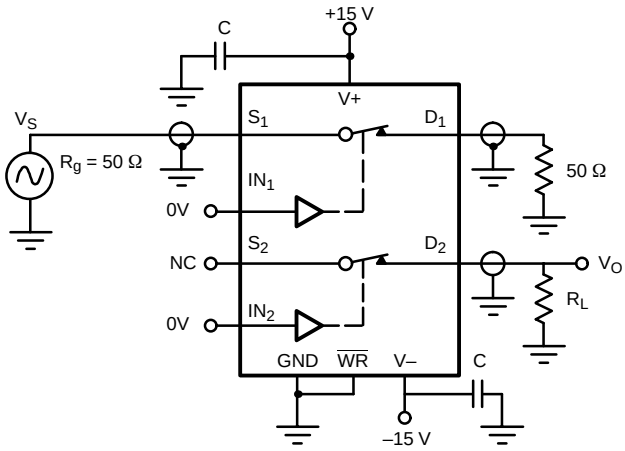
FIGURE 5. Charge Injection



$$\text{Off Isolation} = 20 \log \left| \frac{V_S}{V_O} \right|$$

C = RF bypass

FIGURE 6. Off Isolation



$$X_{TALK}\ \text{Isolation} = 20 \log \left| \frac{V_S}{V_O} \right|$$

C = RF bypass

FIGURE 7. Channel-to-Channel Crosstalk

APPLICATION HINTS[a]

V+ Positive Supply Voltage (V)	V– Negative Supply Voltage (V)	GND (V)	$\overline{WR}$ (V)	V_{IN} Logic Input Voltage $V_{INH(min)}/V_{INL(max)}$ (V)	V_S or V_D Analog Voltage Range (V)
15	–15	0	2.4/0.8	2.4/0.8	–15 to 15
10	–10	0	2.4/0.8	2.4/0.8	–10 to 10
10	–5	0	2.4/0.8	2.4/0.8	–5 to 10

Notes:
a. Application Hints are for DESIGN AID ONLY, not guaranteed and not subject to production testing.

APPLICATIONS

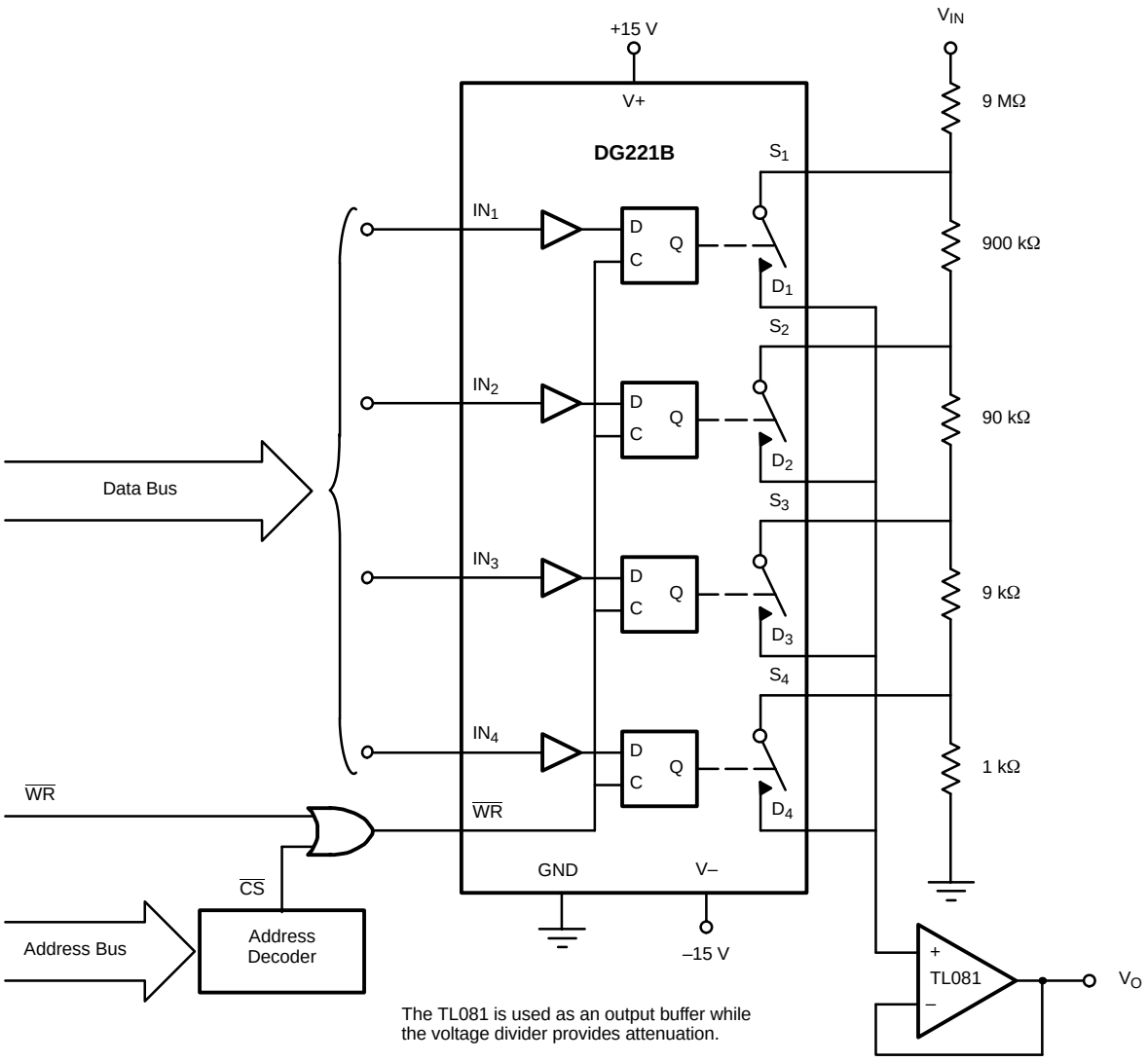


FIGURE 8. μP-Controlled Analog Signal Attenuator

TRUTH TABLE					
IN_1	IN_2	IN_3	IN_4	$\overline{WR}^A$	ON SWITCH
0	0	0	0	0	All
1	1	1	1	0	None
0	1	1	1	0	1
1	0	1	1	0	2
1	1	0	1	0	3
1	1	1	0	0	4

OUTPUT ATTENUATION FOR FIGURE 8					
WR	IN_1	IN_2	IN_3	IN_4	Gain
0	0	1	1	1	0.1
0	1	0	1	1	0.01
0	1	1	0	1	0.001
0	1	1	1	0	0.0001

Notes:
a. $\overline{WR}$ may be held at "0" for temporary operation similar to DG201A/DG201B. With $\overline{WR}$ at "0" SW_1 will remain on as long as IN_1 is held at "0".